ISL6730A, ISL6730B, ISL6730C, ISL6730D

Power Factor Correction Controllers

FN8258
Rev 1.00
August 8, 2013

The ISL6730A, ISL6730B, ISL6730C, ISL6730D are active Power Factor Correction (PFC) controller ICs that use a boost topology. The controllers are suitable for AC/DC power systems, up to 2kW and over the universal line input.

The ISL6730A, ISL6730B, ISL6730C, ISL6730D operate in Continuous Conduction Mode (CCM). Accurate input current shaping is achieved with a current error amplifier. A patent pending breakthrough negative capacitance technology minimizes zero crossing distortion and reduces the magnetic components size. The small external components result in a low cost design without sacrificing performance.

The internally clamped 12.5V gate driver delivers 1.5A peak current to the external power MOSFET. The ISL6730A, ISL6730B, ISL6730C, ISL6730D provide a highly reliable system that is fully protected. Protection features include cycle-by-cycle overcurrent, over power limit, over-temperature, input brownout, output overvoltage and undervoltage protection.

The ISL6730A, ISL6730B provide excellent power efficiency and transitions into a power saving skip mode during light load conditions, thus improving efficiency automatically. The ISL6730A, ISL6730B, ISL6730C, ISL6730D can be shut down by pulling the FB pin below 0.5V or grounding the BO pin. The ISL6730C, ISL6730D have no skip mode.

Two switching frequency options are provided. The ISL6730B, ISL6730D switch at 62kHz, and the ISL6730A, ISL6730C switch at 124kHz.

Features

- Reduce component size requirements
  - Enables smaller, thinner AC/DC adapters
  - Choke and cap size can be reduced
  - Lower cost of materials
- Excellent power factor over line and load regulation
  - Internal current compensation
  - CCM Mode with Patent pending IP for smaller EMI filter
- Better light load efficiency
  - Automatic pulse skipping
  - Programmable or automatic shutdown
- High reliable design
  - Cycle-by-cycle current limit
  - Input average power limit
  - OVP and OTP protection
  - Input brownout protection
- Small 10 Ld MSOP package

Applications

- Desktop computer AC/DC adaptor
- Laptop computer AC/DC adaptor
- TV AC/DC power supply
- AC/DC brick converters

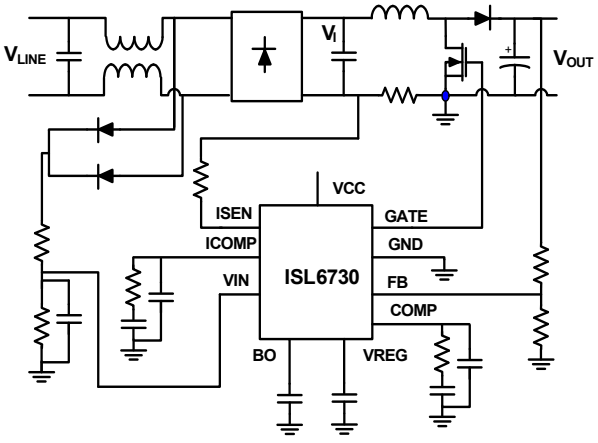


FIGURE 1. TYPICAL APPLICATION

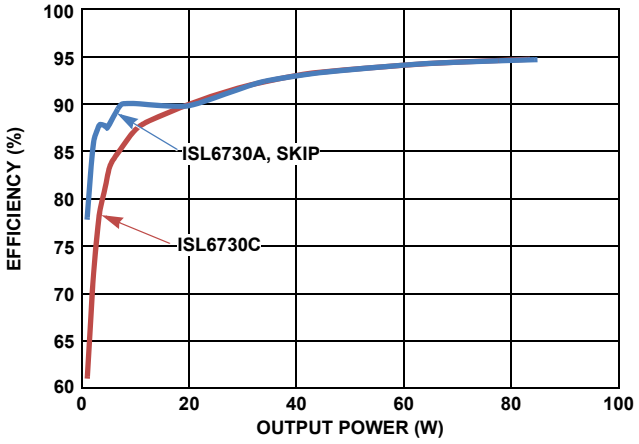


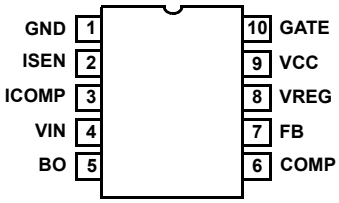
FIGURE 2. PFC EFFICIENCY

TABLE 1. KEY DIFFERENCES IN FAMILY OF ISL6730

VERSION	ISL6730A	ISL6730B	ISL6730C	ISL6730D
Switching Frequency	124kHz	62kHz	124kHz	62kHz
Skip Mode	Yes-Fixed	Yes-Fixed	No	No

Pin Configuration

ISL6730A, ISL6730B, ISL6730C, ISL6730D
(10 LD MSOP)
TOP VIEW



Pin Descriptions

PIN #	I/O	SYMBOL	DESCRIPTION
1	-	GND	Ground pin. All voltage levels refer to this pin.
2	I	ISEN	Current sense pin. The current through this pin is proportional to the inductor current.
3	I/O	ICOMP	Current error amplifier output pin.
4	I	VIN	Input voltage sense. This pin provides the reference voltage to shape inductor current. Connect this pin to a resistor divider from the rectified input voltage. The resistor divider ratio is used to adjust the phase lag between input voltage and the input current. The phase lag is required to compensate the phase lead generated by the EMI filter.
5	I/O	BO	This pin should be decoupled to GND with a minimum 0.1µF ceramic capacitor. The BO pin is a voltage follower, which will follow the DC voltage of the VIN pin. The BO pin is internally tied to GND through a resistor R_{IS}. The decoupling capacitor provides ripple filtering. When the voltage at the BO pin (V_{BO}) drops below brownout voltage threshold, the controller enters shutdown mode and the gate drive is disabled. The BO pin will be disabled when the FB pin drops below the enabling threshold.
6	I/O	COMP	Output of the error amplifier. The voltage of the COMP pin sets the input power. During start-up, a small charge current will slowly ramp up the voltage of the COMP pin.
7	I	FB	Voltage feed back pin. Connect this pin to a resistor divider from the output. The resistor divider sets the output voltage. When the FB pin voltage exceeds 104% of the reference voltage, overvoltage-protection is triggered and gate drive is disabled. When the FB pin is below 10%, the device is put into shutdown mode. There is an internal pull-down current source for open loop protection.
8	-	VREG	Output of internal regulator. The voltage having a ±2% tolerance over line, load and operating temperature. Bypass to GND with a 47nF low ESR capacitor. VREG can source up to 10mA. This pin is not recommended for usage other than bypass.
9	I	VCC	Power supply pin. The VCC pin should be decoupled to GND with a minimum 0.1µF ceramic capacitor.
10	O	GATE	Push-pull gate drive for the external MOSFET. Output voltage is clamped at 12.5V. This pin provides typically 2A sink and 1.5A source capability.

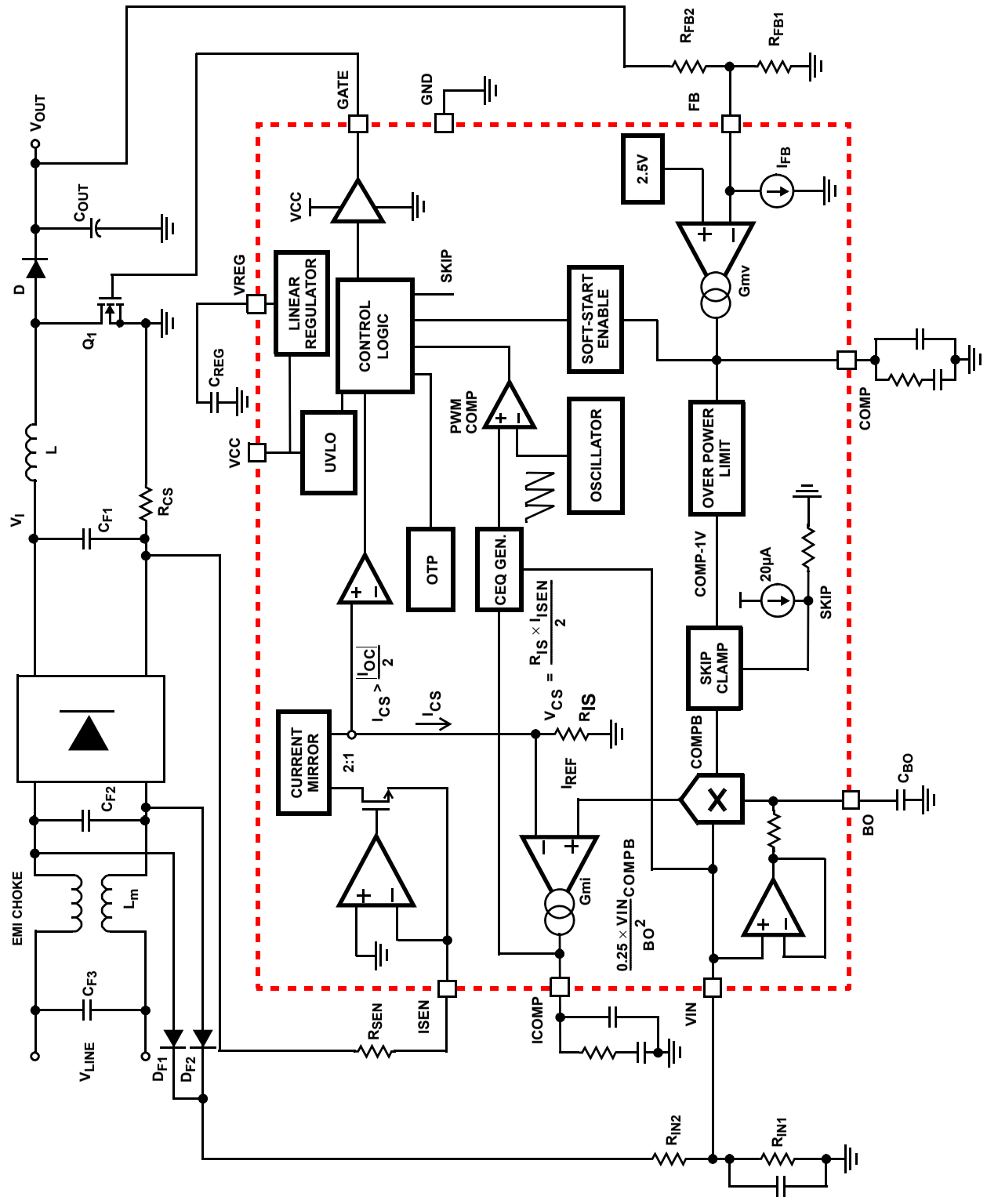
Ordering Information

PART NUMBER (Notes 1, 2, 3)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL6730AFUZ	6730A	-40 to +125	10 Ld MSOP	M10.118
ISL6730BFUZ	6730B	-40 to +125	10 Ld MSOP	M10.118
ISL6730CFUZ	6730C	-40 to +125	10 Ld MSOP	M10.118
ISL6730DFUZ	6730D	-40 to +125	10 Ld MSOP	M10.118
ISL6730AEVAL1Z	Evaluation Board			
ISL6730BEVAL1Z	Evaluation Board			

NOTES:

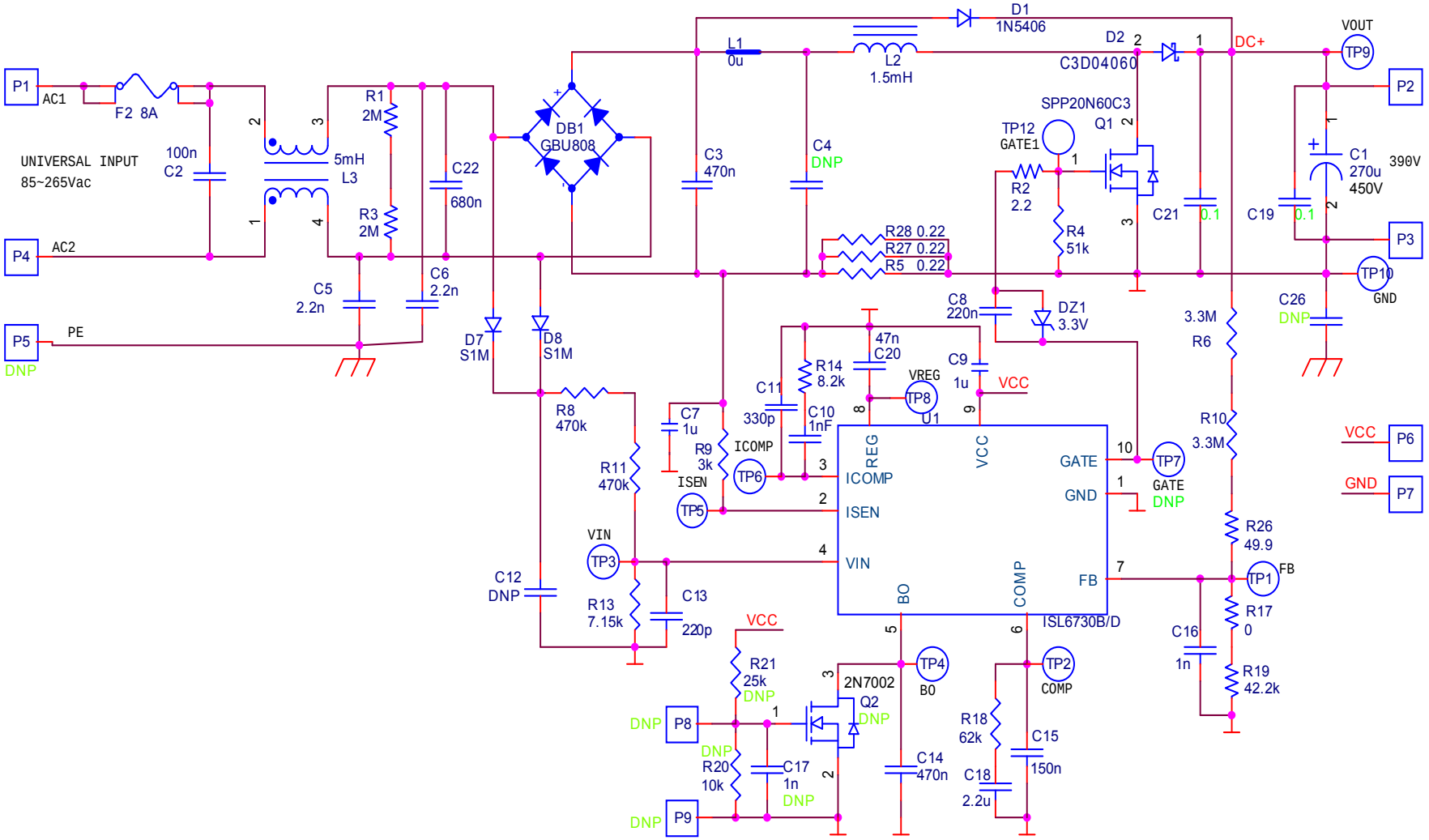
1. Add "-T*" suffix for tape and reel. Please refer to TB347 for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), please see device information page. For more information on MSL please see techbrief TB363.

Block Diagram



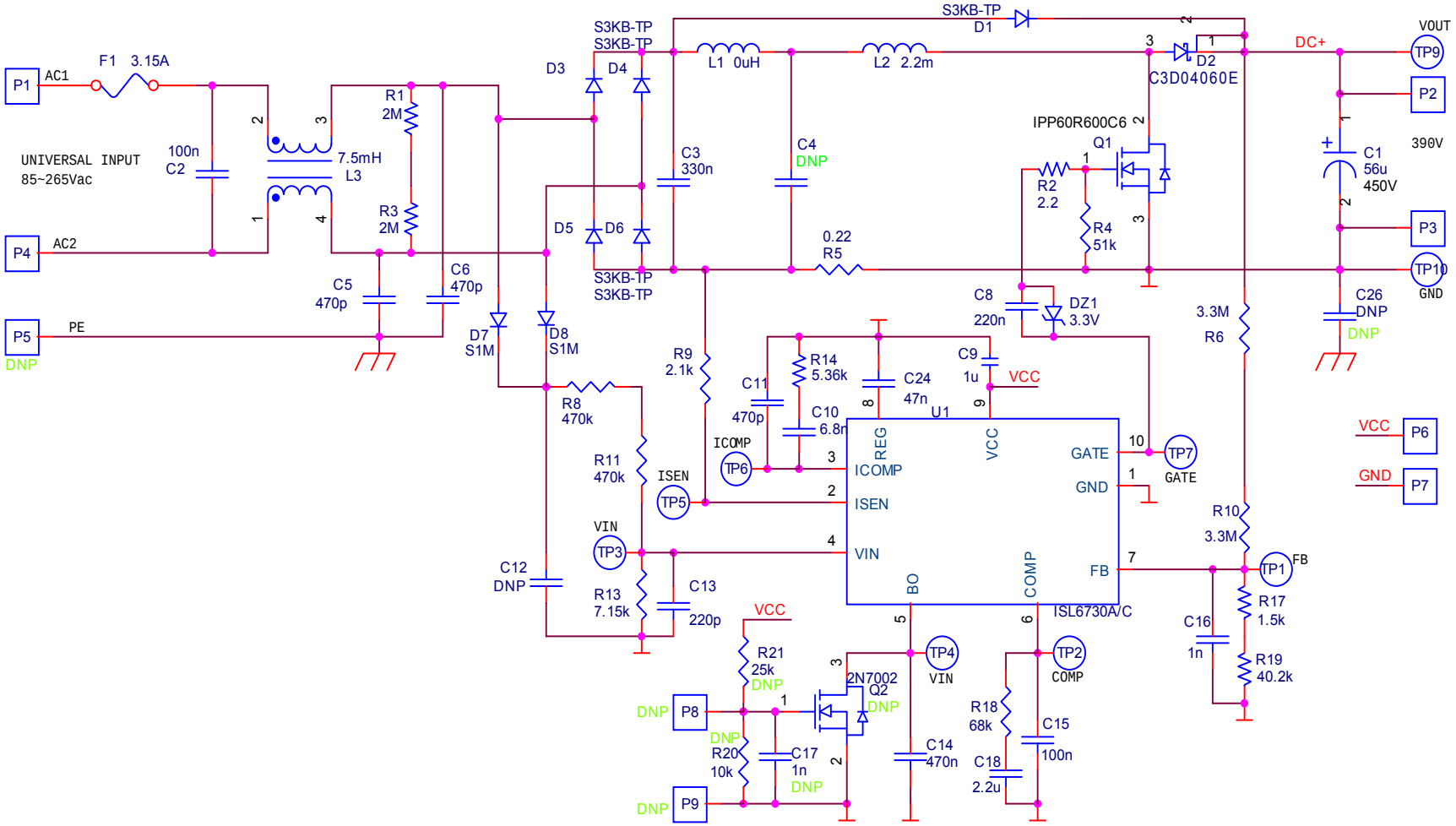
Application Schematics

Typical 300W Application Schematic



Application Schematics (Continued)

Typical 85W Application Schematic



Absolute Maximum Ratings

VCC to GND. . . . . -0.3V to +28V
GATE to GND. . . . . -0.3V to +18V
VIN, BO, ISEN, FB and COMP to GND. . . . . -0.3V to +6.3V
ESD Rating
Human Body Model (Tested per JESD22-A114) 2.5kV
Machine Model (Tested per JESD22-A115). 200V
Charged Device Model (Tested per JESD-C101E. 1kV
Latch Up (Tested per JESD-78B; Class 2, Level A) 100mA

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
MSOP Package (Notes 4, 5)	136.9	39.4

Maximum Junction Temperature (Plastic Package) . . . . . +150°C
Maximum Storage Temperature Range . . . . . -65°C to +150°C
Ambient Temperature Range . . . . . -40°C to +125°C
Junction Temperature Range . . . . . -40°C to +125°C
Pb-Free Reflow Profile . . . . . see link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp

Recommended Operating Conditions

VCC to GND. . . . . 15V to + 20V
Ambient Temperature Range . . . . . -40°C to +125°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

4. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
5. For θ_{JC}, the "case temp" location is taken at the package top center.

Electrical Specifications

Operating Conditions: V_{CC} = 15V, T_A = +25°C. **Boldface limits apply over the operating temperature range, -40°C to +125°C.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
V_{CC} SUPPLY CURRENT						
Start Up Current	I_{START}	V_{FB} = 1V, V_{CC} < V_{CC}(ON)	73	106	139	µA
Standby Current	I_{STDN}	V_{FB} = GND, V_{CC} > V_{CC}(ON)	179	237	295	µA
Skip Mode Current	I_{CCSKIP}	V_{FB} = 2.5V, COMP = SKIP*0.25 +1V	580	690	800	µA
Operating Current (Note 6)	I_{CC}	GATE is floating	3.0	3.7	4.2	mA
VCC UVLO						
UVLO Rising Threshold	$V_{CC(ON)}$		9	10	11	V
UVLO Falling Threshold	$V_{CC(OFF)}$		6.7	7.5	8.3	V
UVLO Threshold Hysteresis	$V_{CC(HYS)}$		-	2.5	-	V
REGULATOR VOLTAGE VREG						
Overall Accuracy	V_{REG}	I_{REG} = 0 to -10mA, V_{CC} = 15V, Load Capacitor = 47nF	5.1	5.4	5.6	V
Current Limit			30	50	70	mA
PWM CONVERTERS						
Maximum Duty Cycle		f_{SW} = 124kHz for ISL6730A/C and f_{SW} = 62kHz for ISL6730B/D	94.8	96.5	-	%
OSCILLATOR						
Free Running Frequency, ISL6730A/C		T_A = -40°C to +125°C, V_{IN} = 0.6V	**98**	107	**116**	kHz
Free Running Frequency, ISL6730A/C		T_A = -40°C to +125°C, V_{IN} = 2.5V	**114**	125	**136**	kHz
Free Running Frequency, ISL6730B/D		T_A = -40°C to +125°C, V_{IN} = 0.6V	**47**	54	**61**	kHz
Free Running Frequency, ISL6730B/D		T_A = -40°C to +125°C, V_{IN} = 2.5V	**57**	64	**71**	kHz
PWM Ramp Amplitude	V_m		1.33	1.46	1.59	V
GATE DRIVER						
Gate Drive Pull-Down Resistance		V_{CC} = 15V, I_{GATE} = 15mA	-	2.33	4.46	Ω
Gate Drive Pull-Up Voltage Drop		V_{CC} = 9V, I_{GATE} = 15mA	0.15	0.3	0.45	V

Electrical Specifications Operating Conditions: V_{CC} = 15V, T_A = +25°C. **Boldface limits apply over the operating temperature range, -40°C to +125°C. (Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
Gate Drive Max. Sourcing/Sinking Current			-	1.5	-	A
Rise Time		C_O = 2.2nF, V_{CC} = 15V, Gate Voltage Rise Time from 10% to 90% of V_{GC}	-	34	62	ns
Fall Time		C_O = 2.2nF, V_{CC} = 15V, Gate Voltage Fall Time from 10% to 90% of V_{GC}	-	34	57	ns
Gate Clamp Voltage	V_{GC}		10.5	12	13.5	V
VOLTAGE REFERENCE						
Reference Voltage	V_{REF}		2.48	2.5	2.52	V
Feedback Pin Pull-Down Current	I_{FB}		-	65	-	nA
Rising Threshold to Enable Converter	FB_EN		280	300	320	mV
Falling Threshold to Disable Converter	FB_DIS		190	202	214	mV
Enable Hysteresis	FB_Hys		-	100	-	mV
VOLTAGE ERROR AMPLIFIER						
Error Amp Transconductance	Gmv		50	77	104	µA/V
ISource/Sink			-	13	-	µA
COMP Offset Voltage	V_{COMP_OFF}		0.95	1.01	1.07	V
COMP Soft-Start Enable Voltage	V_{COMP_EN}		0.58	0.64	0.75	V
INPUT VOLTAGE SENSING						
VIN Leakage Current			-	9	-	nA
MULTIPLIER GAIN						
GMUL		COMP = 2.5V, V_{IN} = 1.0V, BO = 1.0V, I_{SEN} = 50µA	0.196	0.25	0.296	V/V
CURRENT ERROR AMPLIFIER						
Current DC Gain	A_{iDC}	$\Delta I_{ICOMP}/\Delta I_{ISEN}$	1.6	1.9	2.2	A/A
Error Amp Transconductance	Gmi	I_{ICOMP} = ±20µA	205	268	331	µA/V
ICOMP Source/Sink Current (Note 7)			-	60	-	µA
Current Sensing Input Offset			-3	2	7	mV
LIGHT LOAD EFFICIENCY ENHANCEMENT AND OVERPOWER PROTECTION						
Skip Mode COMP Threshold	V_{SCMT}	Applied for ISL6730A/B	1.32	1.36	1.4	V
COMP Upper Limit	V_{CUL}		3.53	3.85	4.17	V
COMP Valid Range	V_{CUL}-1V		2.5	2.83	3.16	V
FB Exit Threshold Voltage	V_{FB_EXIT}	Fraction of the set point (V_{REF}), I_{ISEN} = 0µA, Applied for ISL6730A/B	87	88	89	%
ISEN Exit Threshold Current	I_{SEN_EXIT}	V_{FB} = 2.5V, Applied for ISL6730A/B	-38	-29	-20	µA
BROWNOUT DETECTION						
Brownout Rising Threshold	V_{BO_R}		478	494	510	mV
Brownout Falling Threshold	V_{BO_F}		387	401	415	mV
OVERVOLTAGE PROTECTION						
Overvoltage Protection	V_{OVP}	Fraction of the set point (V_{REF}); ~1µs noise filter	102.9	104.1	105.3	%

Electrical Specifications Operating Conditions: V_{CC} = 15V, T_A = +25°C. **Boldface limits apply over the operating temperature range, -40°C to +125°C. (Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
OVERCURRENT PROTECTION						
Overcurrent Threshold	I_{OC}		-197	-177	-159	µA
THERMAL SHUTDOWN						
Shutdown Temperature (Note 7)			-	160	-	°C
Thermal Shutdown Hysteresis (Note 7)			-	25	-	°C

NOTES:

6. This is the V_{CC} current consumed when the device is active but not switching. Does not include gate drive current.
7. Limits should be considered typical and are not production tested.
8. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified.

Typical Performance Curves

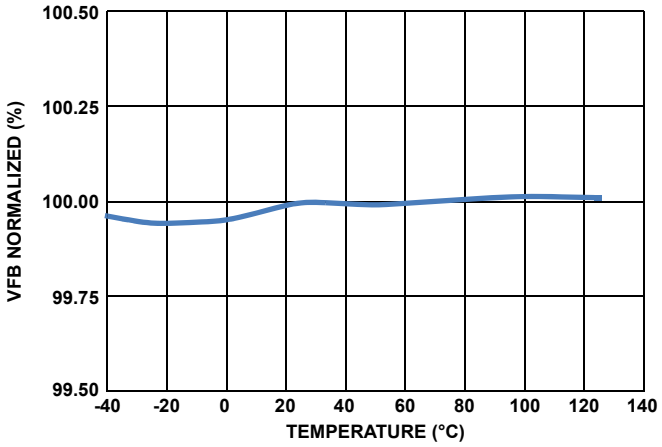


FIGURE 3. FEEDBACK ACCURACY

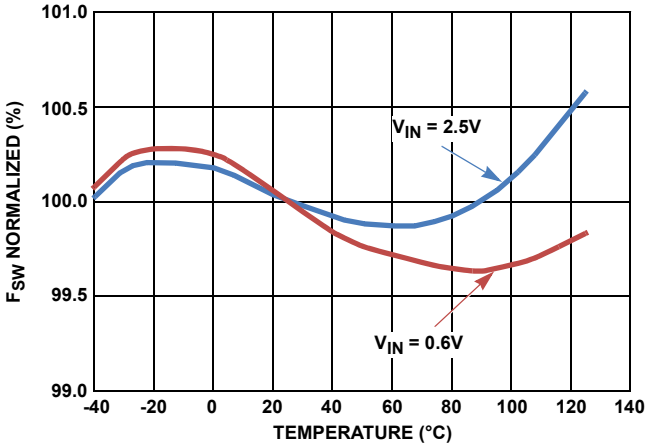


FIGURE 4. F_{SW} vs TEMPERATURE, V_{CC} = 15V

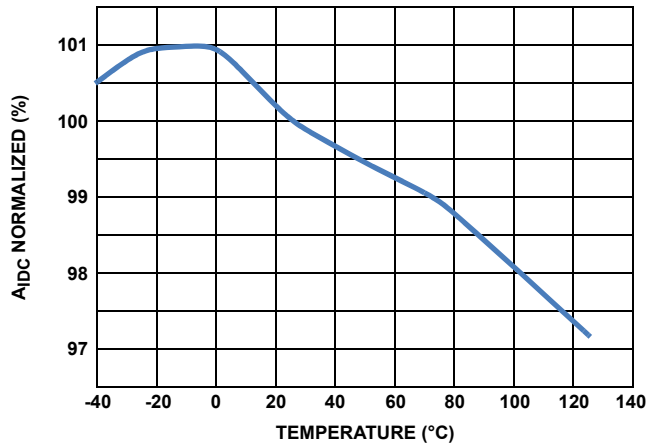


FIGURE 5. A_{IDC} vs TEMPERATURE

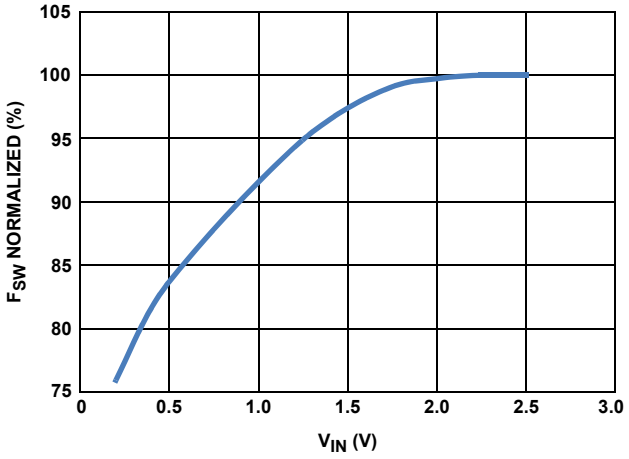


FIGURE 6. F_{SW} vs V_{IN}, T_A = +25°C

Typical Performance Curves (Continued)

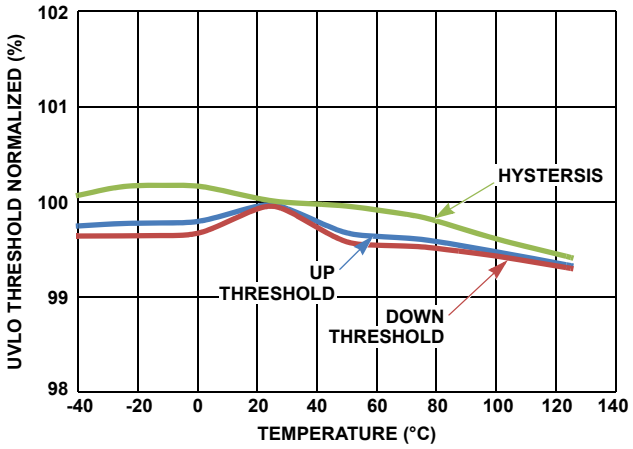


FIGURE 7. UVLO THRESHOLDS vs TEMPERATURE

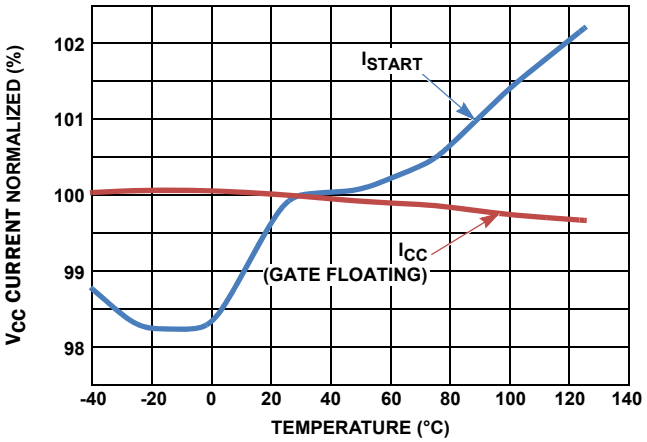


FIGURE 8. V_{CC} SUPPLY CURRENT vs TEMPERATURE

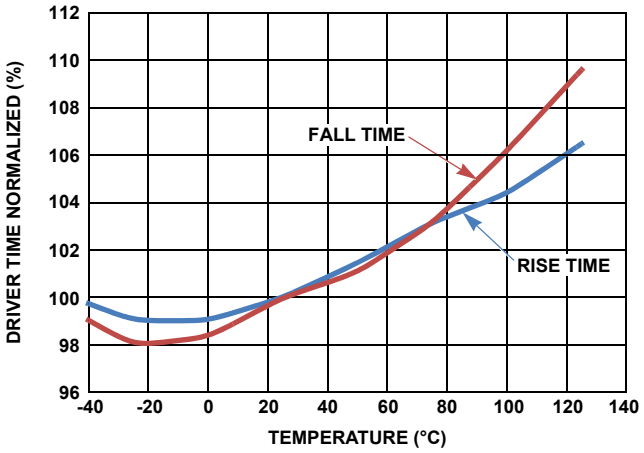


FIGURE 9. GATE DRIVER ABILITY vs TEMPERATURE (LOAD = 2.2nF)

Functional Description

VCC Undervoltage Lockout (UVLO)

The ISL6730A, ISL6730B, ISL6730C, ISL6730D start automatically once the voltage at VCC exceeds the UVLO threshold.

Shutdown

When the VFB pin is below 0.2V, the controller is disabled and the PWM output driver is tri-stated. When disabled, the IC power will be reduced. During shutdown, the COMP pin is discharged to GND and the controller is disabled. The Over-Temperature Protection (OTP) is still alive to prevent the controller from starting up in a high temperature ambient condition.

In the event that the FB pin is disconnected from the feedback resistors, the FB pin is pulled to ground by an internal current source I_{FB}. When the FB pin voltage drops below 0.2V, the gate driver is disabled. The ISL6730A, ISL6730B, ISL6730C, ISL6730D enters shutdown mode.

Soft-Start

The COMP pin is released once the soft-start operation begins. A 13µA current sources out to the RC network connected from the COMP pin until the FB pin voltage reaches 90% of the reference voltage.

Switching is inhibited when the COMP pin voltage is below 1V. When the COMP pin reaches 1V, the current error amplifier and the gate driver are activated and the converter starts switching.

During UVLO, Brownout and Shutdown, the COMP is pulled to the ground.

Input Voltage Sensing

The VIN pin is needed to sense the rectified input voltage. The sensed semi-sinusoidal waveform is needed to shape inductor current, which helps achieves unity power factor. At the same time, the voltage on the VIN pin is used to generate the negative capacitive element at the input. This will cancel the input filter capacitor, C_F. Canceling the effect of C_F will increase the displacement power factor and alleviate the zero crossing distortion, which is related to the distortion power factor.

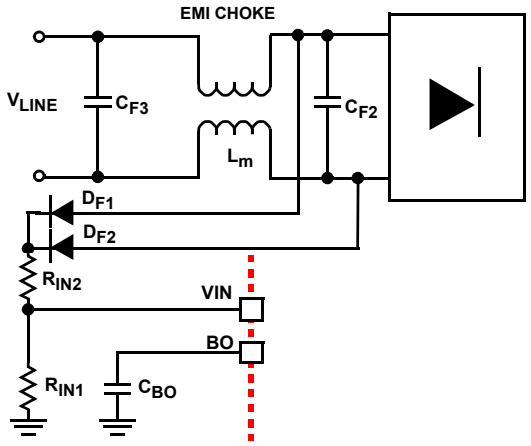


FIGURE 10. INPUT VOLTAGE SENSING SCHEMATIC

The BO pin also utilizes the VIN resistor divider for voltage sensing. Set the resistor divider ratio to satisfy the brownout requirement.

First, calculate the resistor divider ratio, K_{BO}.

$$K_{BO} = \frac{V_{BORMAX}}{V_{RMSmin} - 2V_F} \quad \text{(EQ. 1)}$$

Where V_F is the forward voltage drop of the bridge rectifier and the voltage drop of D_{F1}; D_{F2}.

Then, select the R_{IN2} based on the highest reasonable resistance value. Then select the R_{IN1} based upon the desirable minimum RMS value of the line voltage for the PFC operation.

$$R_{IN1} = \frac{K_{BO}}{1 - K_{BO}} \cdot R_{IN2} \quad \text{(EQ. 2)}$$

Inductor Current Sensing

The current sensing of the converter has two purposes. One is to force the inductor current to track the input semi-sinusoidal waveform. The other purpose is for overcurrent protection. Refer to Figure 11 for the current sensing scheme. The sensed current I_{CS} is in proportion to the inductor current, I_L as described in Equation 3.

$$I_{CS} = \frac{1}{2} \cdot \frac{R_{CS}}{R_{SEN}} \cdot I_L \quad \text{(EQ. 3)}$$

where:

R_{CS} is the current sensing resistor with low value in the return path to the bridge rectifier.

R_{SEN} is the current scaling resistor connected between ISEN to the R_{CS}.

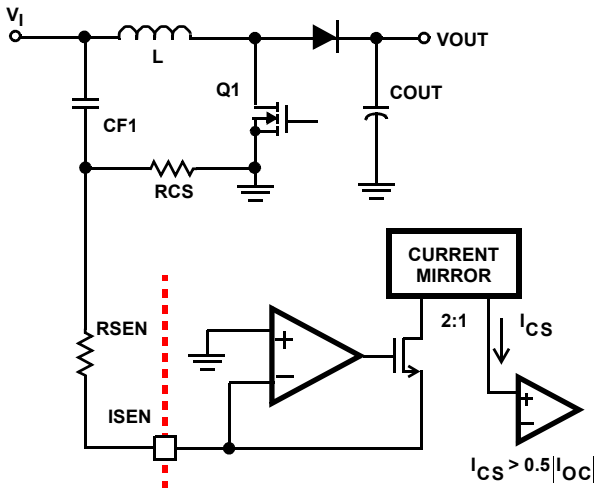


FIGURE 11. INDUCTOR CURRENT SENSING SCHEME

A high value R_{CS} renders more accurate current sensing. It is recommended to use the R_{CS} to render 120mV peak voltage at the maximum line voltage during full load condition.

$$R_{CS} > \frac{120mV \cdot V_{RMSMAX} \cdot \eta}{\sqrt{2} \cdot P_{Omax}} \quad \text{(EQ. 4)}$$

Where η is the efficiency of the converter at the maximum line input with full load.

Since the R_{CS} sees the average input current, high value R_{CS} generates high power dissipation on the R_{CS}. Use a reasonable R_{CS} according to the resistor power rating. The worst-case power dissipation occurs at the input low line when input current is at its maximum. Power dissipation by the resistor is:

$$P_{RCS} = (I_{RMSMAX})^2 \cdot R_{CS} \quad \text{(EQ. 5)}$$

where:

I_{RMSMAX} is the maximum input RMS current at the minimum input line voltage, V_{RMSmin}.

Select the R_{SEN} according to the peak current limit requirement. The resistor is sized for an overload current 25% more than the peak inductor peak current.

Negative Input Capacitor Generation (Patent Pending)

The patent pending negative capacitor generation capability of the ISL6730A, ISL6730B, ISL6730C, ISL6730D allows the capacitor C_{F2} to be moved from before the bridge rectifier (Figure 12) to after the bridge rectifier (Figure 13). Thus, a smaller lower cost C_{F2} can be used. The change in topology reduces the size of the EMI filter. Furthermore, C_{F1} can be increased thus decreasing the size of L_F (Figure 13).

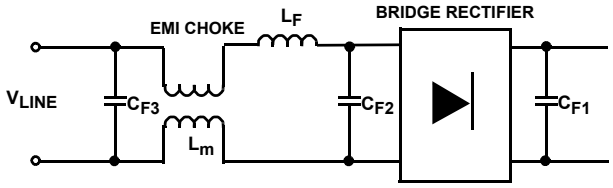


FIGURE 12. TYPICAL PFC INPUT FILTER CIRCUIT

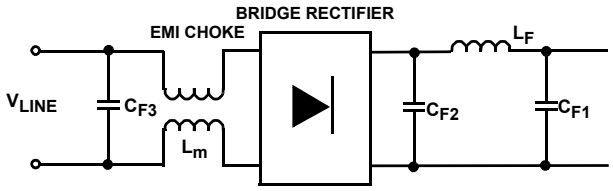


FIGURE 13. LOW COST PFC INPUT FILTER CIRCUIT

For applications where the output power is above 500W, the negative capacitance helps to improve the power factor dramatically. Please refer to Table 2 for the recommended filtering capacitor to be placed after the bridge rectifier, C_{F1}.

TABLE 2.

C_{F1}	Po < 100W	100W < Po < 500W	Po > 500W
Typical C(µF)/100W	0.68	0.33	0.22

Additional C_{F1} may be used to accommodate the use of small boost inductor or to eliminate the differential mode filter inductor as long as the equipment meets the power factor or goal.

The equivalent negative capacitor is a function of the input voltage divider ratio, K_{BO}, the current sensing gain and current compensation error integration gain.

Adjusting the negative Ceq can be achieved by adjusting the current compensation network.

Frequency Modulation

The ISL6730A, ISL6730B, ISL6730C, ISL6730D can further reduce EMI filter size by lowering the differential noise power density. The reduction is achieved by switching frequency modulation.

The frequency varies with the VIN pin. The switching frequency reaches the peak value when the VIN pin voltage is 2V as shown in Figure 6. The peak value of ISL6730A/C is 124kHz, and the ISL6730B/D is 62kHz.

Output Voltage Regulation

The output voltage is sensed through a resistor divider. The middle point of the resistor divider is fed to the FB pin. The resistor divider ratio sets the output voltage. The transconductance error amplifier generates a current in proportion to the difference between the FB pin and the 2.5V internal reference. The PFC is stabilized by the compensation network that is connected from the COMP pin to the ground.

The voltage of the COMP sets the input average power by determining the amplitude of the current reference. To keep the

harmonic distortion minimum, it is desirable to set the control bandwidth much lower than twice of the line frequency. The recommended voltage loop bandwidth is 10Hz.

During start-up, the compensation capacitors and the charging current from the error amplifier sets the input power increase rate. Thus, soft-start is achieved.

The COMP is discharged during shutdown and fault conditions.

Light Load Efficiency Enhancement

For PC, adaptor and TV applications, it is desirable to achieve high efficiency at light load conditions and low standby current. The ISL6730A, ISL6730B can enter light load efficiency mode automatically.

The voltage error amplifier output, COMP, is an indicator of the average input power level. The controller compares the V(COMP) and V(SKIP). If V(COMP)-1V is less than V(SKIP)*0.25, the PFC controller stops gate switching and the COMP pin voltage is clamped to V(SKIP)+0.6V. ISL6730A/B use a fixed V(SKIP), which is 1.4V; for ISL6730C/D, the SKIP function are disabled.

The controller exits skip mode when V_{FB} drops to 88% (typical) of the reference voltage or when the sensed returned current exceeds 29µA.

Protection Circuits

Input Brownout, BO Protection

Brownout occurs when there is a drop in the line voltage. The BO pin is a dual function pin. The BO pin detects the brownout condition and shuts down the gate driver and controller. During normal operation, the BO pin is used to compensate the effect of the input line voltage change on the voltage loop. To keep the harmonic distortion low, the corner frequency formed by the R_{BO} and C_{BO} should be lower than 6Hz.

The BO pin is the output of the average voltage of the rectified voltage. The PFC controller is turned off when the BO pin drops below 0.4V. This protects the PFC power stage to enable operation at or below brownout condition for long periods of time. The controller resumes operation when the BO pin returns to 0.5V.

The BO pin is usually connected to GND through a capacitor, C_{BO}. To avoid distortion on the VIN pin, select C_{BO} so that:

$$C_{BO} \gg 0.22\mu F \quad \text{(EQ. 6)}$$

Overcurrent Protection

The peak current limiting function prevents the inductor from saturation. The gate driver turns off when the current goes above the current limit.

Overpower Protection

The overpower protection is implemented by limiting the COMP pin voltage higher than 3.85V (typical).

Overvoltage Protection

If the voltage on the FB pin exceeds the reference voltage by about 4%, the gate driver is turned off. The controller resumes normal operation after the FB pin drops below reference voltage.

Over-Temperature Protection

The ISL6730A, ISL6730B, ISL6730C, ISL6730D is protected against over-temperature conditions. When the junction temperature exceeds +160°C, the PWM shuts down. Normal operation is resumed when the junction temperature decreases below +135°C.

Application Guidelines

Layout Considerations

As in any high frequency switching converter, layout is very important. Switching current from one power device to another can generate voltage transients across the impedances of the interconnecting bond wires and circuit traces. These interconnecting impedances should be minimized by using wide, short printed circuit traces. The critical components should be located as close together as possible using ground plane construction or single point grounding.

Figure 14 shows the critical power components; Q_1, D and C_{OUT}. To minimize the voltage overshoot, the interconnecting wires indicated by heavy lines should be part of the ground or the power plane in a printed circuit board. The components shown in Figure 14 should be located as close together as possible. Please note that the capacitors C_{VCC} and C_O each represent numerous physical capacitors. Locate the ISL6730A, ISL6730B, ISL6730C, ISL6730D within 2 inches of the MOSFET, Q_1. The circuit traces for the MOSFETs' gate and source connections from the ISL6730A, ISL6730B, ISL6730C, ISL6730D must be sized to handle up to 1.5A peak current.

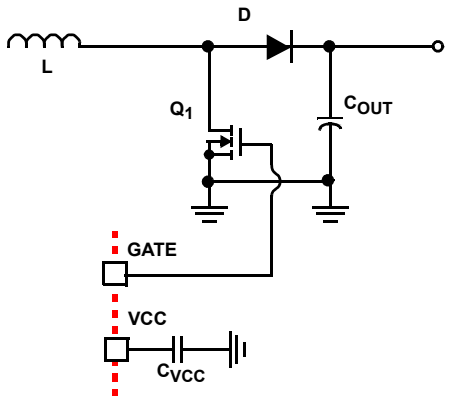


FIGURE 14. CRITICAL CURRENT POWER COMPONENTS

Component Selection Guidelines

A 300W, universal input, PFC converter design is provided for demonstration. The design method is for a continuous current mode power factor correction boost converter with the ISL6730B/D. The switching frequency is 62kHz.

Table 3 shows the design parameters.

TABLE 3. CONVERTER DESIGN PARAMETERS

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
VLINE		85	115	265	VAC
FLINE		47		63	Hz
P_{OMAX}	Maximum Output Power			300	W
T_{HOLD}	Hold Up Time		20		ms
Efficiency	VLINE = 115VAC	92			%

BOOST INDUCTOR SELECTION

First, calculate the maximum input RMS current, I_{INMAX}.

$$I_{INMAX} = \frac{P_{OMAX}}{\eta \bullet V_{RMSmin}} \quad \text{(EQ. 7)}$$

Where η is the converter efficiency at V_{RMSmin}. PF is the power factor at V_{RMSmin}.

$$I_{INMAX} = \frac{300W}{0.92 \bullet 85V} = 3.84A \quad \text{(EQ. 8)}$$

Assuming the current is sinusoidal and the peak to peak ripple at line is 40%.

The boost inductor, L_{BST}, is given by the following equation:

$$L_{BST} \geq \frac{\sqrt{2}V_{RMSmin}}{0.4 \bullet F_{sw} \bullet \sqrt{2} \bullet I_{INMAX}} \bullet \left(1 - \frac{\sqrt{2} \bullet V_{RMSmin}}{V_{OUT}}\right) \quad \text{(EQ. 9)}$$

$$L_{BST} \geq \frac{85V}{0.4 \bullet 62kHz \bullet 3.84A} \bullet \left(1 - \frac{\sqrt{2} \bullet 85V}{390V}\right) = 617\mu H \quad \text{(EQ. 10)}$$

The peak current of the inductor is the sum of the average peak inductor current and half of the peak to peak ripple current. Select and design the boost inductor as given by Equation 11. The ISL6730A, ISL6730B, ISL6730C, ISL6730D provides peak current limit function that can prevent the boost inductor saturation. Assuming 25% margin is given to the OCP threshold, select and design the boost inductor with saturation current given by Equation 11 with 25% more.

$$I_{LPeak} = \sqrt{2} \bullet I_{INMAX} \bullet \left(1 + \frac{0.4}{2}\right) \quad \text{(EQ. 11)}$$

$$I_{LPeak} = \sqrt{2} \bullet 3.88A \bullet \left(1 + \frac{0.4}{2}\right) = 6.5A \quad \text{(EQ. 12)}$$

INPUT RECTIFIER

The maximum average input current is calculated:

$$I_{INAVE(max)} = \frac{2 \bullet \sqrt{2} \bullet I_{INMAX}}{\pi} \quad \text{(EQ. 13)}$$

$$I_{INAVE(max)} = \frac{2 \bullet \sqrt{2} \bullet 3.88A}{\pi} = 3.5A \quad \text{(EQ. 14)}$$

Select the bridge diode using Equation 15 and sufficient reverse breakdown voltage. Assuming the forward voltage, $V_{F,BR}$, is 1V across each rectifier diode. The power loss of the rectifier bridge can be calculated:

$$P_{BR} = 2 \bullet V_{F,BR} \bullet I_{INAVE(MAX)} \quad \text{(EQ. 15)}$$

$$P_{BR} = 2 \bullet 1V \bullet 3.5A = 7W \quad \text{(EQ. 16)}$$

INPUT CAPACITOR SELECTION

Refer to Table 2 for the recommended input filter capacitor value.

$$C_{F1} = 300W \bullet \frac{0.33}{100} = 0.99\mu F \quad \text{(EQ. 17)}$$

This is the recommended capacitor used after the diode bridge. For better power factor, less capacitance can be used. To lower the input filter inductor size, more capacitance can be used.

Two 0.47µF capacitors in parallel are used for C_{F1}.

BOOST DIODE SELECTION

The boost diode loss is determined by the diode forward voltage drop, V_F and the output average current. The maximum output current is:

$$I_{OUT(max)} = \frac{P_{OMAX}}{V_{OUT}} \quad \text{(EQ. 18)}$$

$$I_{OUT(max)} = \frac{300W}{390V} = 0.77A \quad \text{(EQ. 19)}$$

The forward power loss on the diode is:

$$P_{FD} = I_{OUT(max)} \bullet V_F \quad \text{(EQ. 20)}$$

$$P_{FD} = 0.77A \bullet 1.85V = 1.42W \quad \text{(EQ. 21)}$$

The IDD03E60 part is selected.

The reverse recovery loss on the diode can be calculated. The Q_{RR} is found from the diode datasheet. Q_{RR} = 220nC when I_F = 3.5A.

The reverse recover loss on the diode can be estimated:

$$P_{RRD} = \frac{1}{4} \bullet Q_{RR} \bullet V_{OUT} \bullet F_{sw} \quad \text{(EQ. 22)}$$

$$P_{RRD} = \frac{1}{4} \bullet 220nC \bullet 390V \bullet 62kHz = 1.33W \quad \text{(EQ. 23)}$$

The total power loss on the diode is:

$$P_D = P_{FD} + P_{RRD} = (1.42 + 1.35)W = 2.75W \quad \text{(EQ. 24)}$$

MOSFET POWER DISSIPATION

The power dissipation on the MOSFET is from two different types of losses; the condition loss and the switching loss.

For the MOSFET, the worst case is at minimum line input voltage.

First, the drain to source RMS current is calculated:

$$I_{DS(max)} = I_{INMAX}\sqrt{1 - \frac{8\sqrt{2}}{3\pi} \bullet \frac{V_{RMSmin}}{V_{OUT}}} \quad \text{(EQ. 25)}$$

$$I_{DS(max)} = 3.88A\sqrt{1 - \frac{8\sqrt{2}}{3\pi} \bullet \frac{85V}{390V}} = 3.3A \quad \text{(EQ. 26)}$$

The MOSFET, SPP20N60C3 is selected.

$$P_{COND} = I_{DS(max)}^2 \bullet R_{DS(on)} \quad \text{(EQ. 27)}$$

$$P_{COND} = 3.3A^2 \bullet 0.3\Omega = 3.27W \quad \text{(EQ. 28)}$$

The switching loss of the MOSFET consists of three parts: the turn-on loss, the turn-off loss and the diode reverse recovery loss.

From the MOSFET datasheet, the typical switching losses curves are provided.

When $R_G = 3.6\Omega$, $I_D = 6A$, $E_{ON} = 0.015mJ$, $E_{OFF} = 0.007mJ$.

The switching loss due to transition is calculated:

$$P_{SW} = (E_{ON} + E_{OFF}) \bullet F_{sw} \quad \text{(EQ. 29)}$$

$$P_{SW} = (0.015mJ + 0.007mJ) \bullet 62kHz = 1.36W \quad \text{(EQ. 30)}$$

The diode reverse recovery incurs additional power loss on the MOSFET. This loss can be estimated as:

$$P_{RR} = Q_{RR} \bullet V_{OUT} \bullet F_{sw} \quad \text{(EQ. 31)}$$

This loss is also related the di/dt during the MOSFET turn-on. The di/dt can be found out from the MOSFET datasheet. At $R_G = 3.6\Omega$, the turn-on di/dt is 4000A/µs. From the Typical Reverse Recovery Charge curve at $T_J = +125°C$, the $Q_{RR} = 220nC$ when $I_F = 3.5A$.

$$P_{RR} = 220nC \bullet 390V \bullet 62kHz = 5.32W \quad \text{(EQ. 32)}$$

THE TOTAL LOSS ON THE MOSFET

$$P_{COND} + P_{SW} + P_{RR} = 3.27W + 1.36W + 5.32W = 9.95W \quad \text{(EQ. 33)}$$

OUTPUT CAPACITOR SELECTION

The output capacitor, C_{OUT}, is required to hold the output above 300V during one line cycle. For capacitors with 20% tolerance, the tolerance should be taken into consideration. Thus, the output capacitance should be greater than:

$$C_{OUT} \geq \frac{2 \cdot T_{HOLD} \cdot P_{OMAX}}{V_{OUT}^2 - V_{HOLD}^2} \cdot \frac{1}{1 - 0.2} \quad \text{(EQ. 34)}$$

$$C_{OUT} \geq \frac{2 \cdot 20ms \cdot 300W}{(390)^2 - (300V)^2} \cdot 1.25 = 242\mu F \quad \text{(EQ. 35)}$$

Calculate the ripple RMS current through the capacitor:

$$I_{CORMS(max)} = I_{OUT(max)} \sqrt{\frac{8\sqrt{2}}{3\pi} \bullet \frac{V_{OUT}}{V_{RMSmin}} - 1} \quad \text{(EQ. 36)}$$

$$I_{CORMS(max)} = 0.77A \sqrt{\frac{8\sqrt{2}}{3\pi} \bullet \frac{390V}{85V} - 1} = 1.635A \quad \text{(EQ. 37)}$$

Select the proper capacitor according to the hold time and ripple RMS current requirement. The actual capacitance is 270µF.

It is important to make sure the output peak-to-peak ripple is less than the minimum OVP threshold as specified in the "Electrical Specifications" table on page 6. The ESR at 2 times of the line frequency of the capacitor is found in the capacitor datasheet. The ESR of the output capacitor is 770mΩ at 100Hz.

$$V_{Opp} = I_{OUT(max)} \cdot \frac{\sqrt{(4\pi f_{line} \cdot C_{OUT} \cdot ESR)^2 + 1}}{(4\pi f_{line}) \cdot C_{OUT} \cdot 0.8} \quad \text{(EQ. 38)}$$

$$V_{Opp} = 0.77A \cdot \frac{\sqrt{(4\pi \cdot 50Hz \cdot 270\mu F \cdot 0.77\Omega)^2 + 1}}{(4\pi \cdot 50Hz) \cdot 270\mu F \cdot 0.8} = 6.6V \quad \text{(EQ. 39)}$$

The minimum OVP threshold is 103% of the nominal output value. The maximum output peak to peak ripple should be less than 6% of the nominal value, which is $23.4V_{P-P}$.

CURRENT SENSING RESISTORS

Please refer to Equation 4 for calculation of the current sensing resistor R_{CS}.

$$R_{CS} \geq \frac{120mV \cdot 265V \cdot 0.92}{\sqrt{2} \cdot 300W} = 0.069\Omega \quad \text{(EQ. 40)}$$

While a large R_{CS} renders better current sensing accuracy, larger R_{CS} also incurs higher power dissipation. Select R_{CS} from available standard value resistors to determine the sense resistor.

$$R_{CS} = 0.068\Omega \quad \text{(EQ. 41)}$$

The maximum power dissipation on the R_{CS} occurs at low line and full load condition. The maximum power dissipation is calculated:

$$P_{RCSMAX} = I_{INMAX}^2 \bullet R_{CS} \quad \text{(EQ. 42)}$$

$$P_{RCSMAX} = 3.88A^2 \bullet 0.068\Omega = 1.023W \quad \text{(EQ. 43)}$$

The resistor, R_{SEN} sets the overcurrent protection limit. From Equation 3, R_{SEN} should be greater than:

$$R_{SEN} \geq \frac{R_{CS} \bullet I_{LPeak} \bullet (1 + 0.25)}{2 \bullet 0.5|I_{OC}|} \quad \text{(EQ. 44)}$$

Where |x| stands for the ABS(x) function.

$$R_{SEN} \geq \frac{0.068\Omega \bullet 6.6A \bullet 1.25}{2 \bullet 90\mu A} = 3.117k\Omega \quad \text{(EQ. 45)}$$

Select R_{SEN} from available standard value resistors, the selected R_{SEN} is 3.16kΩ.

CURRENT LOOP COMPENSATION

The input current shaping is achieved by comparing the sensed current signal to the sensed input voltage signal. The current error amplifier (Gmi), together with the current compensation network, adjusts the duty cycle so that the inductor current traces the sensed rectified voltage. Thus, unity power factor is achieved.

The compensation network consists of the Trans-Conductance error amplifier (Gmi) and the impedance network (Z_{ICOMP}). The goal of the compensation network is to provide a closed loop transfer function with the sufficient 0dB crossing frequency (f_{0dB}) and adequate phase margin. Phase margin is the difference between the open loop phase at f_{0dB} and 180°. The following equations relate the compensation network's poles, zeros and gain to the components (R_{ic}, C_{ic} and C_{ip}) in Figure 15.

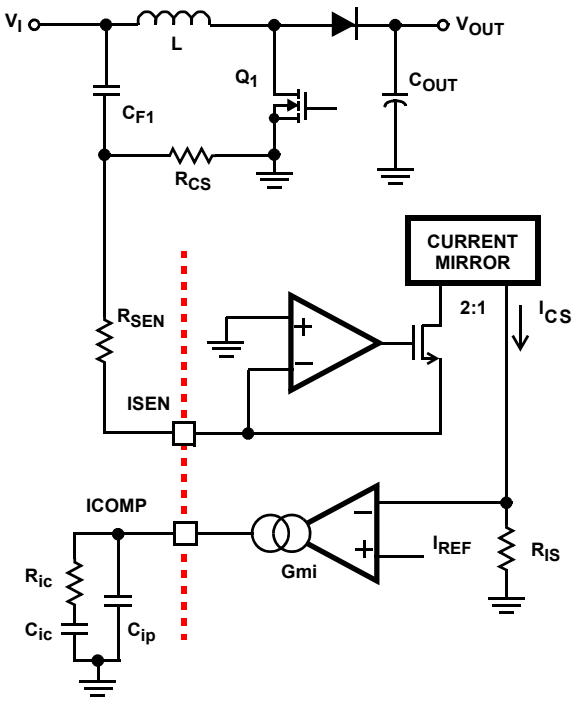


FIGURE 15. INDUCTOR CURRENT SENSING SCHEME

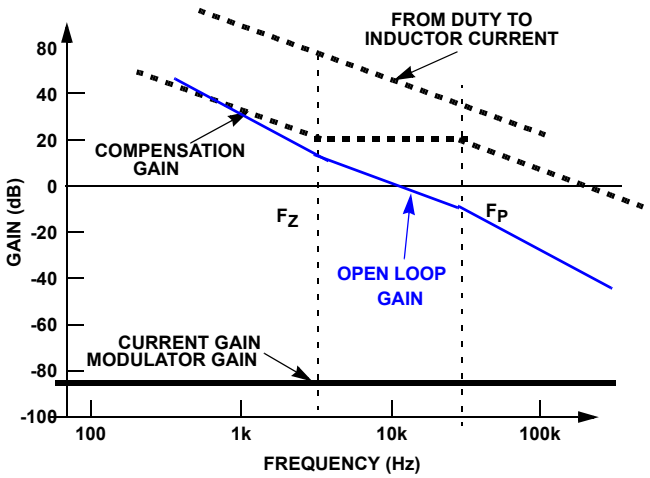


FIGURE 16. ASYMPTOTIC BODE PLOT OF CURRENT LOOP GAIN

$$F_Z = \frac{1}{2\pi \bullet R_{ic} \bullet C_{ic}} \quad \text{(EQ. 46)}$$

$$F_P = \frac{1}{2\pi \bullet R_{ic} \bullet \frac{C_{ip} \bullet C_{ic}}{C_{ip} + C_{ic}}} \quad \text{(EQ. 47)}$$

Use the following guidelines for locating the poles and zeros of the compensation network.

The cross over frequency of the current loop should be set between 2kHz to 100kHz. At cross over frequency, the transfer function from duty cycle to inductor current is well approximated by Equation 48:

$$G_{id}(s) = \frac{V_{OUT}}{L_{BST} \cdot s} \quad \text{(EQ. 48)}$$

It is recommended to set the cross over frequency from 1/10 to 1/6 of the switching frequency with phase margin of 60°. A high frequency pole is set at 1/2 of the switching frequency for ripple filtering. In this example, we set the cross over, F_C at 1/6 of the switching frequency.

$$F_Z = \frac{F_C}{\tan\left(\operatorname{atan}\left(\frac{F_C}{F_P}\right) + \Phi_M\right)} \quad \text{(EQ. 49)}$$

Where $F_C = F_S/6 = 10.3\text{kHz}$, Φ_M is the phase margin, which is 60°. $F_P = F_S/2 = 31\text{kHz}$.

Thus, the current loop compensation zero is:

$$F_Z = \frac{(62\text{KHz})/6}{\tan\left(\operatorname{atan}\left(\frac{2}{6}\right) + 60\text{deg}\right)} = 2.12\text{kHz} \quad \text{(EQ. 50)}$$

The total compensation capacitance is calculated:

$$C_{ip} + C_{ic} = \left(\left(\frac{V_{OUT}}{L_{BST} \cdot (2\pi f_c)^2} \cdot \frac{A_{iDC}}{V_m} \cdot \frac{R_{CS}}{R_{SEN}}\right) \cdot \sqrt{\frac{1 + (f_c/f_z)^2}{1 + (f_c/f_p)^2}}\right) \quad \text{(EQ. 51)}$$

$$C_{ip} + C_{ic} = (19.8)\text{nF} \quad \text{(EQ. 52)}$$

$$C_{ip} = (C_{ip} + C_{iC})\frac{f_z}{f_p} \quad \text{(EQ. 53)}$$

The value of the noise filtering capacitor is:

$$C_{ip} = 14.9\text{nF} \cdot \frac{2.12\text{kHz}}{31\text{kHz}} = 1.35\text{nF} \quad \text{(EQ. 54)}$$

The value of C_{ic} is:

$$C_{ic} = 19.8\text{nF} - 1.35\text{nF} = 18.4\text{nF} \quad \text{(EQ. 55)}$$

The value of R_{ic} is:

$$R_{ic} = \frac{1}{2\pi \cdot 2.12\text{kHz} \cdot 18.4\text{nF}} = 4.11\text{k}\Omega \quad \text{(EQ. 56)}$$

Select the R_C value from the standard value, we have:

$R_{ic} = 4.02\text{k}\Omega$, $C_{ic} = 18\text{nF}$, $C_{ip} = 1.2\text{nF}$. Figure 17 shows the actual bode plot of current loop gain.

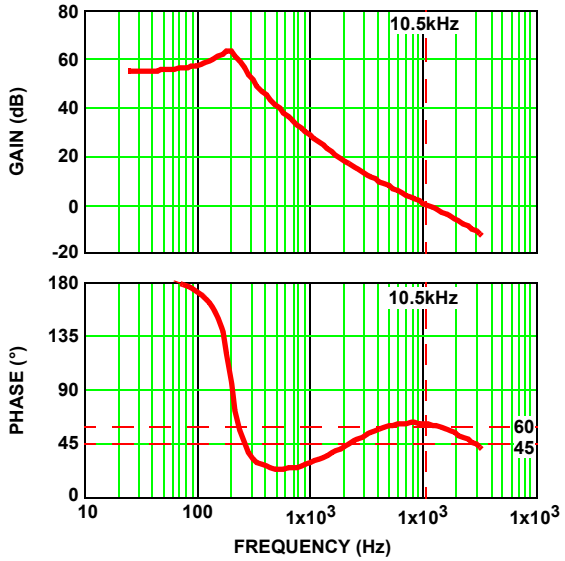


FIGURE 17. BODE PLOT OF THE ACTUAL CURRENT LOOP GAIN

INPUT VOLTAGE SETTING

First, set the BO resistor divider gain, K_{BO} according to Equations 1 and 2.

Assuming the converter starts at V_{LINE} = 80V_{RMS}, then the BO resistor divider gain, K_{BO} should be:

$$K_{BO} = \frac{0.5V}{80V - 2V} = 0.00641 \quad \text{(EQ. 57)}$$

In this design, two 3.3MΩ resistors in series are used for R_{IN2}. So, R_{IN1} is calculated:

$$R_{IN1} = \frac{0.00641}{1 - 0.00641} \cdot (6.6M\Omega) = 42.6k\Omega \quad \text{(EQ. 58)}$$

Using resistor from the standard value, R_{IN1} = 43kΩ, the actual K_{BO} is calculated:

$$K_{BO} = \frac{R_{IN1}}{R_{IN1} + R_{IN2}} = 0.00647 \quad \text{(EQ. 59)}$$

NEGATIVE INPUT CAPACITOR GENERATION

The ISL6730A, ISL6730B, ISL6730C, ISL6730D generates an equivalent negative capacitance at the input to cancel the input filter capacitance. Thus, more input capacitors can be used without reducing the power factor.

The input equivalent negative capacitance is a function of the current sensing gain, BO resistor divider gain and the compensation components.

$$C_{NEG} = \left(K_{BO} \cdot 0.8 - \frac{V_m}{V_{OUT}}\right)\frac{R_{SEN}}{R_{CS}A_{iDC}}(C_{ic} + C_{ip}) \quad \text{(EQ. 60)}$$

$$C_{NEG} = \left(0.00647 \cdot 0.8 - \frac{1.5}{390}\right)\frac{3.16k}{0.068 \cdot 1.9}(18nF + 1.2nF) = 0.62\mu F \quad \text{(EQ. 61)}$$

This equivalent negative capacitor cancels the input filter capacitor required for EMI filtering. Therefore, the displacement power factor significantly improves.

For example, C_{F2} = 0.68µF, C_{F1} = 0.94µF, using the low cost EMI filter shown in Figure 13. When V_{LINE} = 230VAC, f_{LINE} = 50Hz, P_O = 60W.

Assuming 95% efficiency under the above test condition, the resistive component, which is in phase to voltage:

$$I_a = \frac{P_o}{V_{LINE} \cdot 0.95} = 0.275A \quad \text{(EQ. 62)}$$

The reactive current through the input capacitors:

$$I_c = V_{LINE} \bullet (2\pi \cdot f_{LINE}) \bullet (C_{F1} + C_{F2}) = 0.117A \quad \text{(EQ. 63)}$$

Thus, the displacement power factor is:

$$PF_{DIS} = \frac{I_a}{\sqrt{(I_a)^2 + (I_c)^2}} = 0.92 \quad \text{(EQ. 64)}$$

The reactive current generated by the equivalent negative capacitor is:

$$I_{cneg} = V_{LINE} \bullet (2\pi \cdot f_{LINE}) \bullet (C_{NEG}) = 0.045A \quad \text{(EQ. 65)}$$

With the equivalent negative capacitor, the total reactive current reduces to:

$$I_c - I_{cneg} = 0.072A \quad \text{(EQ. 66)}$$

The displacement power factor increases to:

$$PF_{DIS} = \frac{I_a}{\sqrt{(I_a)^2 + (I_c - I_{cneg})^2}} = 0.967 \quad \text{(EQ. 67)}$$

VOLTAGE LOOP COMPENSATION

The average diode forward current can be approximated by:

$$I_{D(ave)} = \frac{P_{in}}{V_{OUT}} \quad \text{(EQ. 68)}$$

Assuming the input current traces the input voltage perfectly. The input power is in proportion to (V_{COMP} - 1V).

$$I_{D(ave)} = \frac{R_{SEN}}{R_{CS} \cdot 0.5 \cdot R_{IS}} \bullet \frac{1}{V_{OUT}} \bullet \left(\frac{0.25}{((2\sqrt{2})/\pi)^2 \cdot K_{BO}}\right) \bullet \Delta_{COMP} \quad \text{(EQ. 69)}$$

Where Δ_{COMP} is the V_{COMP} - 1V. 1V is the offset voltage.

R_{IS} is the internal current scaling resistor. R_{IS} = 14.2kΩ.

$$I_{D(ave)} = 0.598\frac{A}{V} \bullet \Delta_{COMP} \quad \text{(EQ. 70)}$$

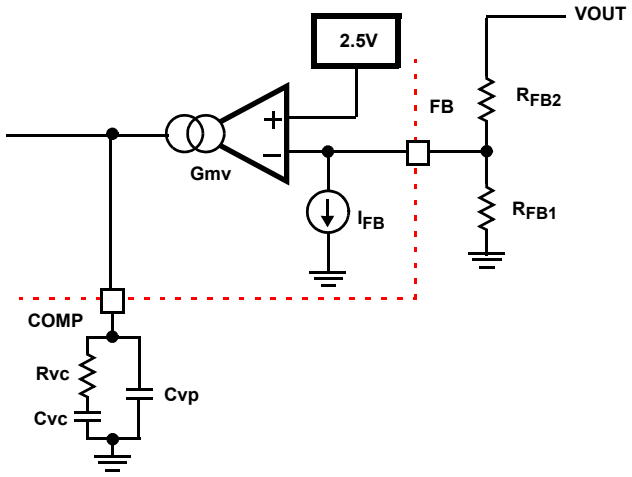


FIGURE 18. OUTPUT VOLTAGE SENSING AND COMPENSATION

Thus, the transfer function from $\overline{V}_{COMP}$ to $\overline{V}_{OUT}$ is:

$$G_{PS}(s)=\frac{V_{OUT}(s)}{\Delta_{COMP}}=\frac{1}{C_O\cdot s}\cdot\frac{I_{D(ave)}}{\Delta_{COMP}} \quad \text{(EQ. 71)}$$

$$G_{PS}(s)=\left(\frac{I_{D(ave)}}{C_O\cdot s}\cdot\frac{1}{\Delta_{COMP}}\right)=\frac{0.598}{C_O\cdot s} \quad \text{(EQ. 72)}$$

As shown in Figure 18, the voltage loop gain is:

$$G_{VLOOP}(s)=G_{PS}(s)\bullet G_{DIV}\bullet gmv\bullet Z_{COMP}(s) \quad \text{(EQ. 73)}$$

The output feedback resistor divider gain, G_{DIV} is:

$$G_{DIV}=\frac{V_{REF}}{V_{OUT}} \quad \text{(EQ. 74)}$$

The compensation gain uses external impedance networks as shown in Figure 18, $Z_{COMP}(s)$ is given by:

$$Z_{COMP}(s)=\frac{1}{(C_{vc}+C_{vp})\cdot s}\bullet\frac{R_{vc}\bullet C_{vc}\bullet s+1}{\frac{R_{vc}\bullet C_{vc}\bullet C_{vp}}{C_{vc}+C_{vp}}\bullet s+1} \quad \text{(EQ. 75)}$$

The targeted cross over frequency, F_{CV} is 8Hz. The high frequency pole, F_{PV} is required in order to reject the 2 time line frequency component. F_{PV} = 20Hz. The targeted phase margin is 60°.

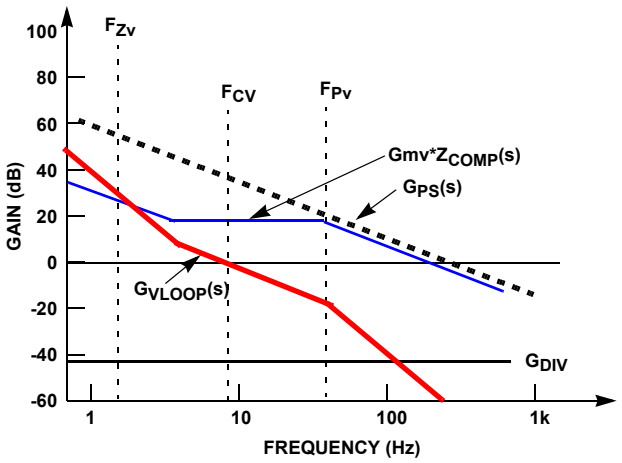


FIGURE 19. ASYMPTOTIC BODE PLOT OF CURRENT LOOP GAIN

The zero, F_{Zv} is calculated:

$$F_{Zv}=\frac{F_{CV}}{\tan(\Phi_m+\operatorname{atan}(F_{CV}/(F_{Pv})))} \quad \text{(EQ. 76)}$$

$$F_{Zv}=\frac{8Hz}{\tan(60deg+\operatorname{atan}((8Hz)/(20Hz)))}=1.15Hz \quad \text{(EQ. 77)}$$

Then the total capacitance used for compensation is calculated:

$$C_{vc}+C_{vp}=\frac{|G_{PS}(i\bullet(2\pi F_{CV}))|\bullet G_{DIV}\bullet Gmv}{(2\pi F_{CV})}\bullet\sqrt{\frac{(F_{CV}/F_{ZV})^2+1}{(F_{CV}/F_{PV})^2+1}} \quad \text{(EQ. 78)}$$

Thus, the total compensation capacitance is:

$$C_{vc}+C_{vp}=1829nF \quad \text{(EQ. 79)}$$

$$C_{vp}=1829nF\bullet\frac{F_{ZV}}{F_{PV}}=105nF \quad \text{(EQ. 80)}$$

$$C_{vc}=1829nF-105nF=1724nF \quad \text{(EQ. 81)}$$

$$R_{vc}=\frac{1}{2\cdot\pi\cdot F_{ZV}\cdot C_{VC}}=81.2k\Omega \quad \text{(EQ. 82)}$$

Choose components from the standard values. We have C_{VP} = 100nF, C_{VC} = 1500nF, R_{VC} = 82.5kΩ. The actual bode plot is shown in Figure 20.

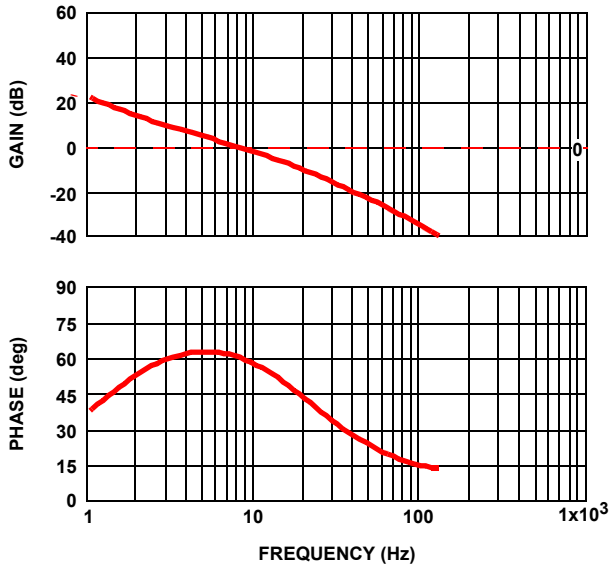


FIGURE 20. BODE PLOT OF THE ACTUAL VOLTAGE LOOP GAIN

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
August 8, 2013	FN8258.1	Added electronic specifications to parts ISL6730B/D and made necessary changes throughout document.
February 26, 2013	FN8258.0	Initial Release.

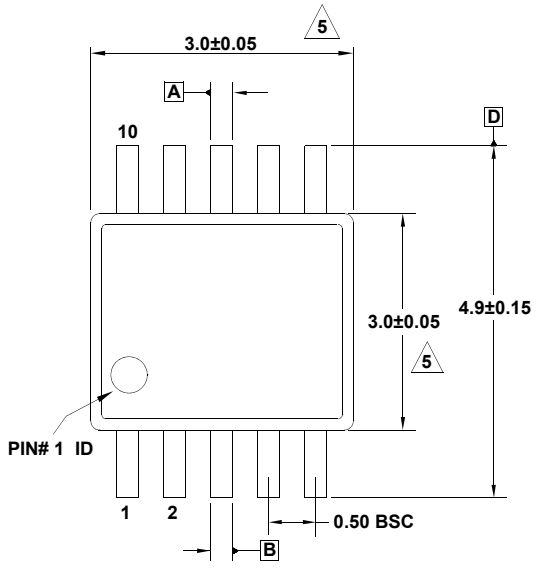
About Intersil

Intersil Corporation is a leader in the design and manufacture of high-performance analog, mixed-signal and power management semiconductors. The company's products address some of the largest markets within the industrial and infrastructure, personal computing and high-end consumer markets. For more information about Intersil, visit our website at www.intersil.com.

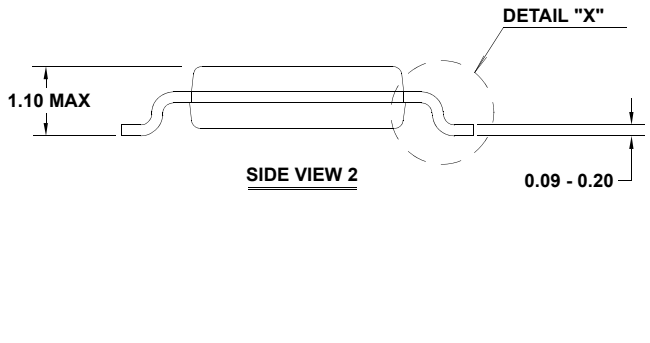
For the most updated datasheet, application notes, related documentation and related parts, please see the respective product information page found at www.intersil.com. You may report errors or suggestions for improving this datasheet by visiting www.intersil.com/en/support/ask-an-expert.html. Reliability reports are also available from our website at http://www.intersil.com/en/support/qualandreliability.html#reliability

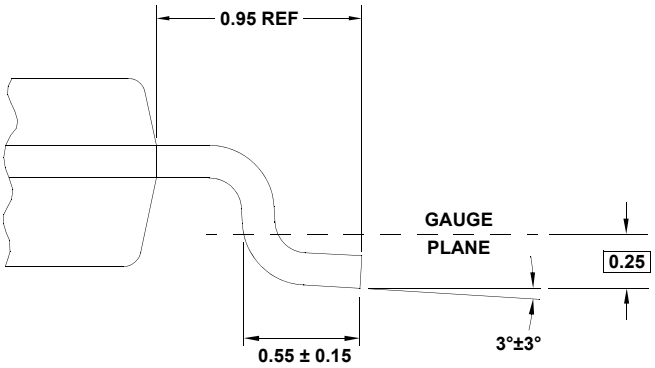
Package Outline Drawing
M10.118
10 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

Rev 1, 4/12

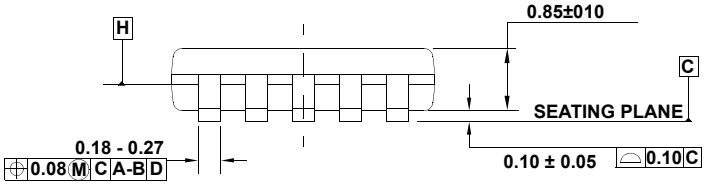


TOP VIEW

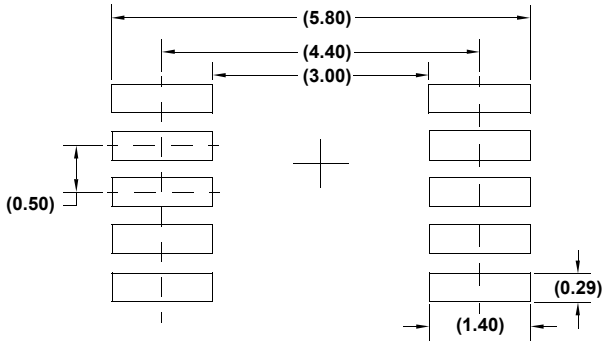




DETAIL "X"



SIDE VIEW 1



TYPICAL RECOMMENDED LAND PATTERN

NOTES:

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-BA and AMSEY14.5m-1994.
3. Plastic or metal protrusions of 0.15mm max per side are not included.
4. Plastic interlead protrusions of 0.15mm max per side are not included.
5. Dimensions are measured at Datum Plane "H".
6. Dimensions in ( ) are for reference only.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Renesas Electronics:

ISL6730DEVAL1Z ISL6730BEVAL1Z ISL6730AEVAL1Z ISL6730CEVAL1Z